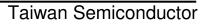
## MBR2535CT - MBR25150CT



#### 5 TAIWAN SEMICONDUCTOR

# 25A, 35V - 150V Schottky Barrier Rectifier

#### **FEATURES**

- AEC-Q101 qualified available
- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

### **MECHANICAL DATA**

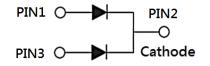
- Case: TO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.90g (approximately)

| KEY PARAMETERS     |          |      |  |
|--------------------|----------|------|--|
| PARAMETER          | VALUE    | UNIT |  |
| I <sub>F</sub>     | 25       | А    |  |
| V <sub>RRM</sub>   | 35 - 150 | V    |  |
| I <sub>FSM</sub>   | 200      | А    |  |
| T <sub>J MAX</sub> | 150      | °C   |  |
| Package            | TO-220AB |      |  |
| Configuration      | Dual d   | lies |  |









| ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)                  |                     |                   |                   |                   |                   |                   |                    |                    |      |
|--|---------------------|-------------------|-------------------|-------------------|-------------------|-------------------|--------------------|--------------------|------|
|  |                     | MBR               | MBR               | MBR               | MBR               | MBR               | MBR                | MBR                |      |
| PARAMETER  | SYMBOL              | 2535              | 2545              | 2550              | 2560              | 2590              | 25100              | 25150              | UNIT |
|  |                     | СТ                | СТ                | СТ                | СТ                | СТ                | СТ                 | СТ                 |      |
| Marking code on the device   |                     | MBR<br>2535<br>CT | MBR<br>2545<br>CT | MBR<br>2550<br>CT | MBR<br>2560<br>CT | MBR<br>2590<br>CT | MBR<br>25100<br>CT | MBR<br>25150<br>CT |      |
| Repetitive peak reverse voltage  | V <sub>RRM</sub>    | 35                | 45                | 50                | 60                | 90                | 100                | 150                | V    |
| Reverse voltage, total rms value   | V <sub>R(RMS)</sub> | 24                | 31                | 35                | 42                | 63                | 70                 | 105                | V    |
| Forward current  | I <sub>F</sub>      |                   |                   |                   | 25                |                   |                    |                    | Α    |
| Surge peak forward current, 8.3ms<br>single half sine wave<br>superimposed on rated load | I <sub>FSM</sub>    |                   |                   |                   | 200               |                   |                    |                    | A    |
| Peak repetitive reverse surge current <sup>(1)</sup>                                     | I <sub>RRM</sub>    | -                 | 1                 |                   |                   | 0.5               |                    |                    | Α    |
| Peak repetitive forward current<br>(Rated V <sub>R</sub> , Square wave, 20KHz)           | I <sub>FRM</sub>    |                   |                   | ·                 | 25                |                   |                    |                    | Α    |
| Critical rate of rise of off-state voltage   | dv/dt               |                   |                   |                   | 10,00             | 0                 |                    |                    | V/µs |
| Junction temperature   | TJ                  |                   |                   | -                 | 55 to +           | 150               |                    |                    | °C   |
| Storage temperature  | T <sub>STG</sub>    |                   |                   | -                 | 55 to +           | 150               |                    |                    | °C   |

Notes:

1. tp = 2.0µs, 1.0KHz



# MBR2535CT – MBR25150CT Taiwan Semiconductor

| THERMAL PERFORMANCE                 |                  |     |      |
|-------------------------------------|------------------|-----|------|
| PARAMETER                           | SYMBOL           | ТҮР | UNIT |
| Junction-to-case thermal resistance | R <sub>eJC</sub> | 1   | °C/W |

| <b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^{\circ}C$ unless otherwise noted) |  |  |                |     |           |        |
|--|--|--|----------------|-----|-----------|--------|
| PARAMETER  |  | CONDITIONS                                     | SYMBOL         | ТҮР | MAX       | UNIT   |
|  | MBR2535CT<br>MBR2545CT<br>MBR2550CT<br>MBR2560CT |  |                | -   | -<br>0.75 | V<br>V |
|  | MBR2590CT<br>MBR25100CT                          |  |                | -   | 0.85      | V      |
|  | MBR25150CT                                       |  |                | -   | 0.95      | V      |
|  | MBR2535CT<br>MBR2545CT                           |  |                | -   | 0.82      | V      |
|  | MBR2550CT<br>MBR2560CT                           | I <sub>F</sub> = 25.0A, T <sub>J</sub> = 25°C  |                | -   | -         | V      |
|  | MBR2590CT<br>MBR25100CT                          |  |                | -   | 0.92      | V      |
| Forward voltage per  | MBR25150CT                                       |  | VF             | -   | 1.02      | V      |
| diode <sup>(1)</sup>   | MBR2535CT<br>MBR2545CT                           |  |                | -   | -         | V      |
|  | MBR2550CT<br>MBR2560CT                           |  |                | -   | 0.65      | V      |
|  | MBR2590CT<br>MBR25100CT                          |  |                | -   | 0.75      | V      |
|  | MBR25150CT                                       |  |                | -   | 0.92      | V      |
|  | MBR2535CT<br>MBR2545CT                           | I <sub>F</sub> = 25.0A, T <sub>J</sub> = 125°C |                | -   | 0.73      | V      |
|  | MBR2550CT<br>MBR2560CT                           |  |                | -   | -         | V      |
|  | MBR2590CT<br>MBR25100CT                          |  |                | -   | 0.88      | V      |
|  | MBR25150CT                                       |  |                | -   | 0.98      | V      |
| Reverse current @ rated $V_R$ per diode <sup>(2)</sup>                         | MBR2535CT<br>MBR2545CT<br>MBR2550CT<br>MBR2560CT | T₁ = 25°C                                      | I <sub>R</sub> | -   | 200       | μΑ     |
|  | MBR2590CT<br>MBR25100CT<br>MBR25150CT            |  |                | -   | 100       | μΑ     |
|  | MBR2535CT<br>MBR2545CT                           | T <sub>J</sub> = 125°C                         |                | -   | 15        | mA     |
|  | MBR2550CT<br>MBR2560CT                           |  |                | -   | 10        | mA     |
|  | MBR2590CT<br>MBR25100CT                          |  |                | -   | 7.5       | mA     |
|  | MBR25150CT                                       |  |                | -   | 5         | mA     |

#### Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms



# MBR2535CT – MBR25150CT Taiwan Semiconductor

## ORDERING INFORMATION

| ORDERING CODE <sup>(1)(2)</sup> | PACKAGE  | PACKING   |
|---------------------------------|----------|-----------|
| MBR25xCT                        | TO-220AB | 50 / Tube |
| MBR25xCTH                       | TO-220AB | 50 / Tube |

Notes:

1. "x" defines voltage from 35V(MBR2535CT) to 150V(MBR25150CT)

2. "H" means AEC-Q101 qualified



1000

## MBR2535CT – MBR25150CT

Taiwan Semiconductor

#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

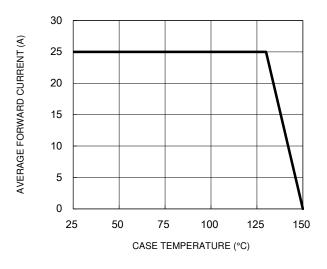
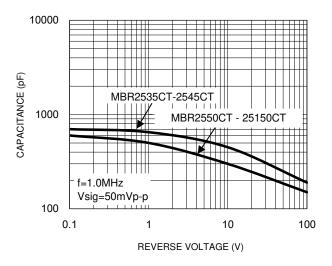
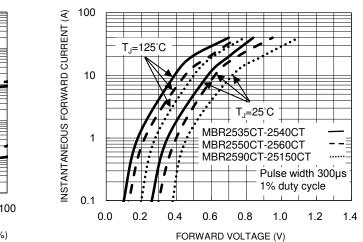


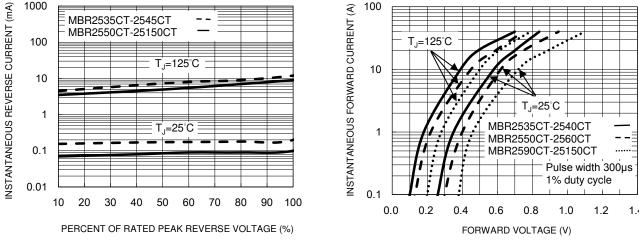
Fig.1 Forward Current Derating Curve

#### **Fig.3 Typical Reverse Characteristics**

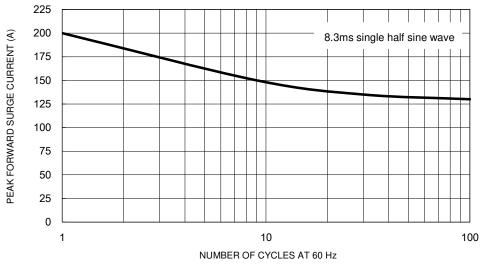


#### **Fig.4 Typical Forward Characteristics**





#### Fig.5 Maximum Non-Repetitive Forward Surge Current



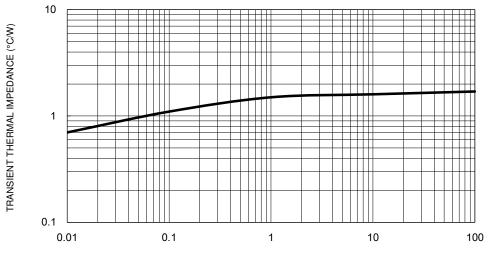
## **Fig.2 Typical Junction Capacitance**



Taiwan Semiconductor

### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 



#### Fig.6 Typical Transient Thermal Impedance

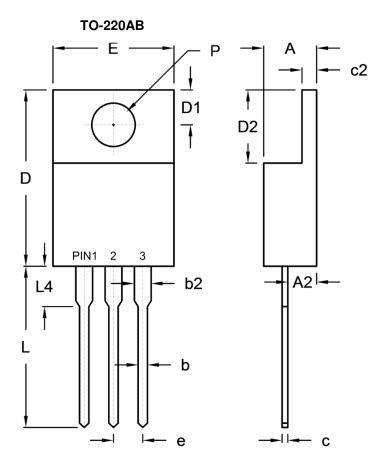
PULSE DURATION (s)



# MBR2535CT - MBR25150CT

Taiwan Semiconductor

## **PACKAGE OUTLINE DIMENSIONS**



| DIM. | Unit (mm) |       | Unit ( | (inch) |  |
|------|-----------|-------|--------|--------|--|
|      | Min.      | Max.  | Min.   | Max.   |  |
| A    | 4.42      | 4.76  | 0.174  | 0.187  |  |
| A2   | 2.20      | 2.80  | 0.087  | 0.110  |  |
| b    | 0.68      | 0.94  | 0.027  | 0.037  |  |
| b2   | 1.14      | 1.77  | 0.045  | 0.070  |  |
| с    | 0.35      | 0.64  | 0.014  | 0.025  |  |
| c2   | 1.14      | 1.40  | 0.045  | 0.055  |  |
| D    | 14.60     | 16.00 | 0.575  | 0.630  |  |
| D1   | 2.62      | 3.44  | 0.103  | 0.135  |  |
| D2   | 5.84      | 6.86  | 0.230  | 0.270  |  |
| E    | -         | 10.50 | -      | 0.413  |  |
| е    | 2.41      | 2.67  | 0.095  | 0.105  |  |
| L    | 13.19     | 14.79 | 0.519  | 0.582  |  |
| L4   | 2.80      | 4.20  | 0.110  | 0.165  |  |
| Р    | 3.54      | 4.00  | 0.139  | 0.157  |  |

#### **MARKING DIAGRAM**



| P/N | = Marking Code   |
|-----|------------------|
| G   | = Green Compound |
| YWW | = Date Code      |
| F   | = Factory Code   |



# MBR2535CT - MBR25150CT

Taiwan Semiconductor

## Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies.

Purchasers are solely responsible for the choice, selection, and use of TSC products and TSC assumes no liability for application assistance or the design of Purchasers' products.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.